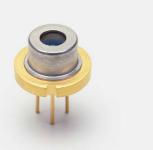


# **Super luminescent diode (SLD)**



L11607-04 L12856-04

### High-power super luminescent diode

SLD (Super Luminescent Diode) is an infrared light-emitting device that combines the high brightness of a laser diode with the low coherence of an LED. It was developed as a high-brightness light source that compensates for the disadvantages of laser diodes such as coherence noise, and is suitable for applications that require high S/N, such as optical gyroscopes, medical imaging, and optical application measurement.

### Features

- High brightness
- Low coherency
- ➡ Center wavelength: 875 nm typ. (L11607-04) 830 nm typ. (L12856-04)
- Built-in photodiode for monitoring (L12856-04)

### Applications

- Optical gyroscope
- Medical imaging
- **■** Light source for displacement measurement

### Absolute maximum ratings (Tcase=25 °C, unless otherwise noted)

Parameter	Symbol	L11607-04	L12856-04	Unit
Radiant flux	фе	35	15	mW
Forward current	IF	140	185	mA
Reverse voltage (SLD)	VRs	1.5		
Reverse voltage (PD)*1	VRd	-	20	V
Operating temperature (case)*2	Tcase	0 to +50	-10 to +70	°C
Storage temperature*2	Tstg	-20 to +80		

<sup>\*1:</sup> Photodiode for output monitoring

When there is a temperature difference between a product and the surrounding area in high humidity environments, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

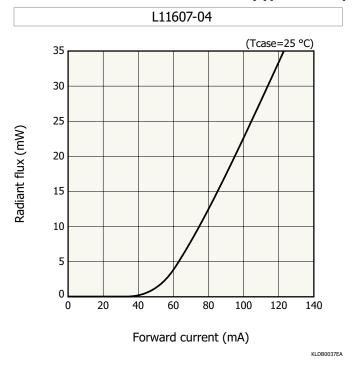
### **■** Electrical and optical characteristics (Tcase=25 °C, unless otherwwise noted)

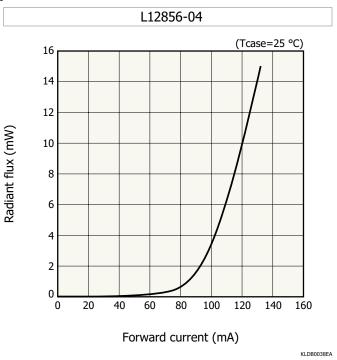
Parameter		Symbol Condition	Condition	L11607-04* <sup>3</sup>			L12856-04* <sup>3</sup>			Unit
			Condition	Min.	Тур.	Max.	Min.	Тур.	Max.	UIIIL
Center wavelength	١	λс		855	875	895	820	830	840	nm
Spectral half-width	1	Δλ		7	10	13	5	10	20	nm
Operating voltage		Vop		-	1.7	1.9	-	1.8	2.2	V
Operating current		Iop		-	110	125	-	120	170	mA
Beam spread angle	Horizontal	θ//	FWHM	6	11	16	4	8	12	. 0
	Vertical	θ⊥		26	36	46	28	36	44	
Coherent length		Lc	Design value	-	70	-	-	70	-	μm
Output monitor current		Im		-	-	-	-	0.12	-	mA
Emission area		-	Design value	-	5 × 1	-	-	5 × 1	-	μm

<sup>\*3:</sup> L11607-04 фe=30 mW, L12856-04 фe=10 mW

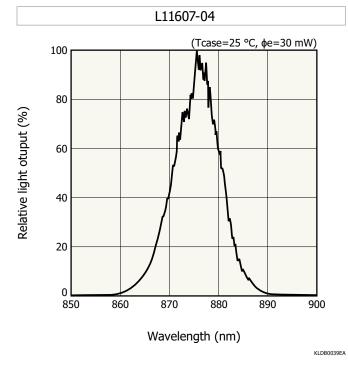
<sup>\*2:</sup> No dew condensation

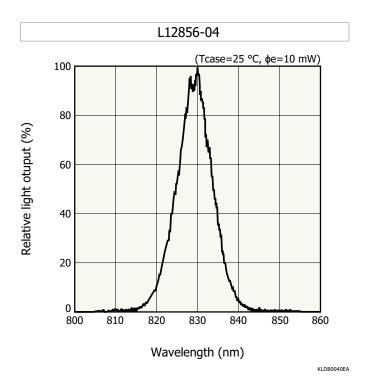
### Radiant flux vs. forward current (typical example)



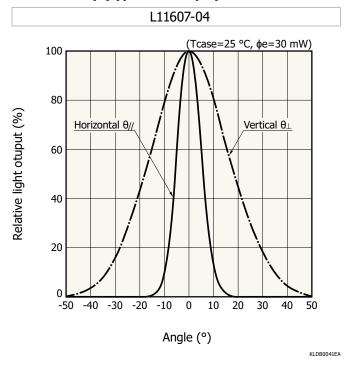


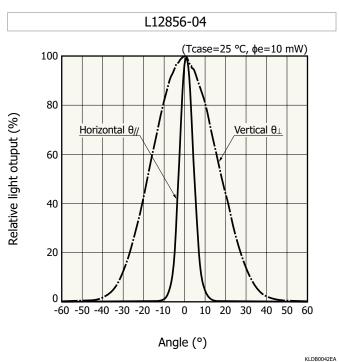
### **Emission spectrum (typical example)**



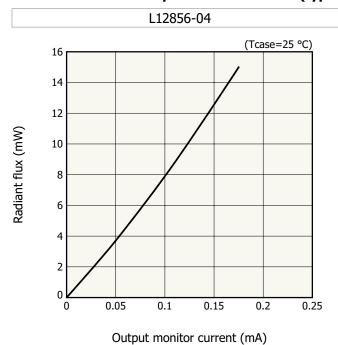


### Directivity (typical example)





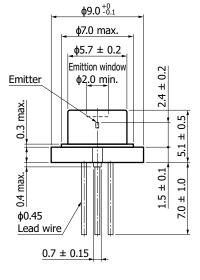
- Radiant flux vs. Output monitor current (typical example)

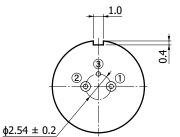


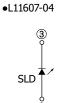


KLDB0043EA

### Dimensional outline (unit: mm)







① NC ② SLD anode ③ SLD cathode

(case)

# 

PD anode
 SLD cathode
 SLD anode

●L12856-04

③ SLD anode PD cathode (case) FFP horizontal and vertical directions relative to the package (front view)

relative to the package (front view)				
	ф9.0 PKG			
θ// Horizontal direction				
θ⊥ Vertical direction				

KLDA0008EA

### Recommended soldering conditions

· Soldering temperature: 260 °C or less, within 5 seconds (1 second or less if the lead terminal length is 2 mm or less) Note: When you set soldering conditions, check that problems do not occur in the product by testing out the conditions in advance.

### Warning (Class 3B laser) Invisible laser emission: Avoid exposure to the beam

This product falls under the "Class 3B laser" in the classification of laser products according to IEC 60825-01. The laser light emitted by this product is an invisible laser light that cannot be seen by the naked eye. Observing the laser light directly is dangerous, and you should also avoid direct exposure to the skin. In addition, some conditions may cause skin damage or flammable substances to ignite.

When using equipment incorporating this product, please classify it according to IEC 60825-01.

Class 3B Laser



**<b>∆WARNING** LASER RADIATION WEAR EYE-PROTECTORS

Label for wearing protective goggles

Note: For more detailed information, please see [IEC 60825-1:2014].

### Precautions

(1) Electrostatic countermeasures

To prevent damage due to static electricity, take electrostatic countermeasures such as grounding of workers, work benches, and work tools. For details, please refer to the related information "Precautions / Compound opto-semiconductors (photosensors, light emitters)". Also protect this device from surge voltages which might be caused by peripheral equipment.

(2) Reflected light

The product will be destroyed if it is irradiated with laser light, such as by regular reflection. When using this product, use extra caution to avoid irradiation of reflected light.

### Related information

www.hamamatsu.com/sp/ssd/doc\_en.html

- Precautions
- Disclaimer
- · Safety consideration / Opto-semiconductor products
- · Precautions / Compound opto-semiconductors (photosensors, light emitters)

The content of this document is current as of April 2025.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

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